

2SA1627A

PNP EPITAXIAL SILICON TRANSISTOR

DESCRIPTION

The UTC 2SA1627A is designed for general purpose amplifier and high speed switching applications.

FEATURES

- * High voltage
- * Low collector saturation voltage.
- * High-speed switching

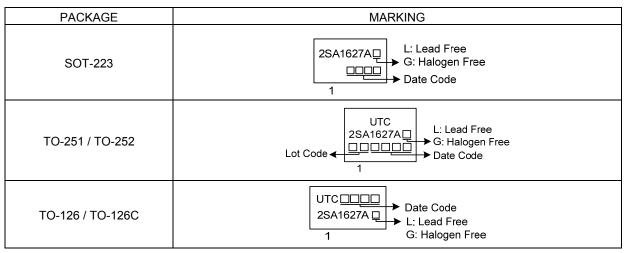
ORDERING INFORMATION

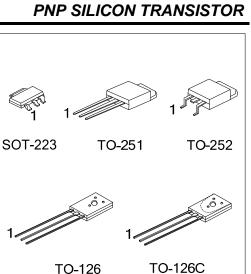
Number	Dookogo	Pin Assignment			Deaking	
Halogen Free	Раскаде	1	2	3	Packing	
2SA1627AG-x-AA3-R	SOT-223	В	С	Е	Tape Reel	
2SA1627AG-x-TM3-T	TO-251	В	С	Е	Tube	
2SA1627AG-x-TN3-R	TO-252	В	С	Е	Tape Reel	
2SA1627AG-x-T60-K	TO-126	Е	С	В	Bulk	
2SA1627AG-x-T6C-K	TO-126C	Е	С	В	Bulk	
	Halogen Free 2SA1627AG-x-AA3-R 2SA1627AG-x-TM3-T 2SA1627AG-x-TN3-R 2SA1627AG-x-T60-K	Halogen Free Package 2SA1627AG-x-AA3-R SOT-223 2SA1627AG-x-TM3-T TO-251 2SA1627AG-x-TN3-R TO-252 2SA1627AG-x-T60-K TO-126	Halogen Free Package 1 2SA1627AG-x-AA3-R SOT-223 B 2SA1627AG-x-TM3-T TO-251 B 2SA1627AG-x-TN3-R TO-252 B 2SA1627AG-x-T60-K TO-126 E	Halogen Free Package 1 2 2SA1627AG-x-AA3-R SOT-223 B C 2SA1627AG-x-TM3-T TO-251 B C 2SA1627AG-x-TN3-R TO-252 B C 2SA1627AG-x-T60-K TO-126 E C	Halogen Free Package 1 2 3 2SA1627AG-x-AA3-R SOT-223 B C E 2SA1627AG-x-TM3-T TO-251 B C E 2SA1627AG-x-TN3-R TO-252 B C E 2SA1627AG-x-TN3-R TO-252 B C E 2SA1627AG-x-T60-K TO-126 E C B	

Note: Pin Assignment: E: Emitter	C: Collector	B: Base
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2SA1627A <u>G-x-T6C-K</u> (1)Packing Type (2)Package Type (3)Rank (4)Green Package	 (1) K: Bulk, R: Tape Reel, T: Tube (2) AA3: SOT-223, TM3: TO-251, TN3: TO-252 T6C: TO-126C, T60: TO-126 (3) x: reference to Classification of h_{FE1} (4) G: Halogen Free and Lead Free, L: Lead Free
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MARKING





■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C, unless otherwise specified)

PARAMETI	ER	SYMBOL	RATINGS	UNIT
Collector-Base Voltage		V _{CBO}	-600	V
Collector-Emitter Voltage		V _{CEO}	-600	V
Emitter-Base Voltage		V _{EBO}	-7.0	V
Collector Power Dissipation	SOT-223		0.8	W
	TO-251/TO-252	Pc	1.9	W
	TO-126/TO-126C		1.0	W
Collector Current (DC)		Ι _C	-1.0	А
Collector Current (Pulse) (Note 2)		I _{CP}	-2.0	А
Junction Temperature		TJ	+150	°C
Storage Temperature		T _{STG}	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS (T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector Cut-Off Current	I _{CBO}	V _{CB} = -600V, I _E =0			-10	μA
Emitter Cut-Off Current	I _{EBO}	V _{EB} = -7.0V, I _C =0			-10	μA
DC Current Gain (Note 2)	h _{FE1}	V _{CE} = -5.0V, I _C = -0.1A	30		120	
	h _{FE2}	V _{CE} = -5.0V, I _C = -0.5A	4			
Collector-Emitter Saturation Voltage(Note)	V _{CE(SAT)}	I _C = -0.3A, I _B = -0.06A		-0.28	-1.5	V
Base-Emitter Saturation Voltage(Note)	V _{BE(SAT)}	I _C = -0.3A, I _B = -0.06A		-0.85	-1.2	V
Gain Bandwidth Product	f⊤	V _{CE} = -10V, I _E =0.1A	10	28		MHz
Output Capacitance	COB	V _{CB} = -10V, I _E =0, f=1.0MHz		42	50	pF
Turn-On Time	t _{ON}			0.1	0.5	μs
Storage Time	T _{SYG}	I _C =-0.5A, R _L =500Ω, I _{B1} = -I _{B2} = -0.1A, V _{CC} =-250V		3.5	5.0	μs
Fall Time	t⊧	$ B_1 - B_2 - C_1 $ $ B_1 - B_2 - C_2 $		0.08	0.5	μs

Note: Pulsed PW \leq 350µs, Duty Cycle \leq 2%

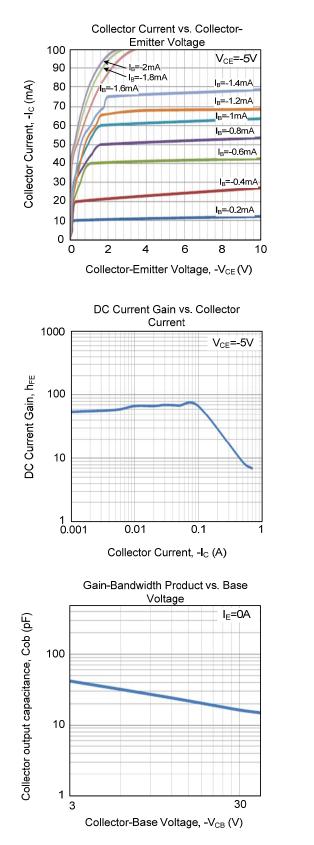
CLASSIFICATION OF h_{FE1}

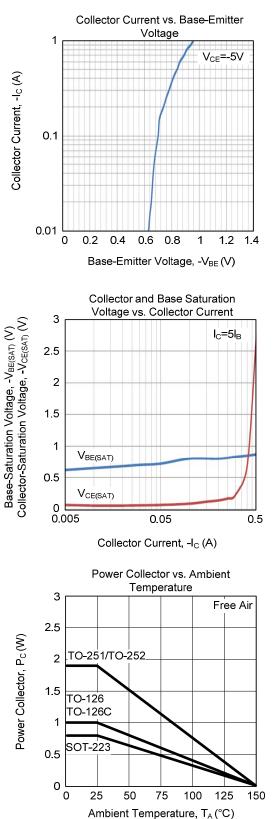
RANK	М	L	К
RANGE	30-60	40-80	60-120



^{2.} $P_W\! \le\! 10ms,$ Duty Cycle $\! \le\! 50\%$

TYPICAL CHARACTERISTICS

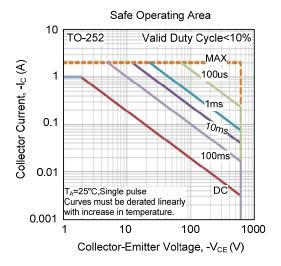






2SA1627A

■ TYPICAL CHARACTERISTICS (Cont.)



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